

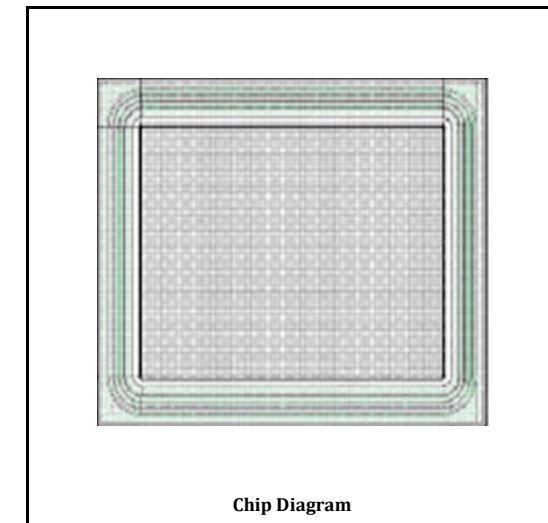
**PRODUCT FEATURES**

- ◆ Ultrafast Recovery Time
- ◆ Soft Recovery Characteristics
- ◆ Low Forward Voltage
- ◆ Low Leakage Current
- ◆ Low Recovery Loss

**Applications (not limited to)**

- ◆ Freewheeling, Snubber, Clamp
- ◆ Snubber Diode
- ◆ Switch Power Supplies
- ◆ Motor control
- ◆ Inverters, Converters

| Items             | Description     |
|-------------------|-----------------|
| Wafer Size        | 5 Inch          |
| Gross Die         | 1700 EA         |
| Top Metal         | Al              |
| Back Metal        | Ag              |
| Dimensions        | um              |
| Chip Size         | 2360μm * 2700μm |
| Pad Size          | 1950μm * 2290μm |
| Wafer Thickness   | 260±20μm        |
| Scribe Line width | 50 μm           |
| Bonding Wire      | Al, 15mil*1     |


**Absolute Maximum ratings ( $T_a=25^\circ\text{C}$ )**

| Parameter                              | Symbol    | Value   | Units            |
|--|-----------|---------|------------------|
| DC Blocking Voltage                    | $V_{RRM}$ | 200     | V                |
| Average Rectified Forward Current      | $I_{FAV}$ | 20      | A                |
| Nonrepetitive Peak Surge Current@8.3ms | $I_{FSM}$ | 200     | A                |
| Operating Junction Temperature         | $T_J$     | 175     | $^\circ\text{C}$ |
| Storage Temperature                    | $T_{STG}$ | -55~150 | $^\circ\text{C}$ |

**Electrical specification ( $T_a=25^\circ\text{C}$ )**

| Parameter                 | Symbol   | Test Conditions  | Min | Typ  | Max  | Units         |
|---------------------------|----------|--|-----|------|------|---------------|
| Reverse Breakdown Voltage | $V_{BR}$ | $I_R=50\mu\text{A}$                                    | 200 | 250  | -    | V             |
| Forward Voltage           | $V_F$    | $I_F=20\text{A}, T_a=25^\circ\text{C}$                 | -   | 0.98 | 1.05 | V             |
|                           |          | $I_F=20\text{A}, T_a=125^\circ\text{C}$                | -   | 0.83 | 0.95 | V             |
| Reverse Leakage Current   | $I_R$    | $V_R=200\text{V}, T_a=25^\circ\text{C}$                | -   | -    | 2    | $\mu\text{A}$ |
|                           |          | $V_R=200\text{V}, T_a=125^\circ\text{C}$               | -   | -    | 50   | $\mu\text{A}$ |
| Reverse Recovery Time     | $T_{rr}$ | $I_F=0.5\text{A}, I_R=1\text{A}, I_{rr}=0.25\text{A}$  | -   | 19   | 30   | ns            |
|                           |          | $I_F=1\text{A}, V_R=30\text{V}, di/dt=-200\text{A/us}$ | -   | 21   | -    | ns            |

**Remark:**

- 1.Customer should obtain the latest version of datasheet before placing order, and verify the relevant information.
- 2.Cutting damage and chipping area can't beyond scribe line in given size range.
- 3.Testing system of Trr could be different, customer might take secondary test to evaluate if necessary.
- 4.Customer might choose the bonding wire material and diameter according to actual situation ,while no less than our recommendation.